

BSI Standards Publication

Surface chemical analysis — Depth profiling — Non-destructive depth profiling of nanoscale heavy metal oxide thin films on Si substrates with medium energy ion scattering



BS ISO 23170:2022 BRITISH STANDARD

National foreword

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A list of organizations represented on this committee can be obtained on request to its committee manager.

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Analyse chimique des surfaces — Profilage d'épaisseur — Profilage d'épaisseur non destructif de films minces d'oxydes de métaux lourds à l'échelle nanométrique sur des substrats de Si par diffusion d'ions de moyenne énergie

